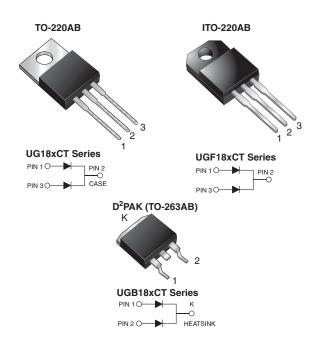
UG18xCT, UGF18xCT, UGB18xCT

Vishay General Semiconductor

Dual Common Cathode Ultrafast Plastic Rectifier



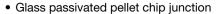
DESIGN SUPPORT TOOLS AVAILABLE



PRIMARY CHARACTERISTICS						
I _{F(AV)}	18 A					
V_{RRM}	50 V to 200 V					
I _{FSM}	175A					
t _{rr}	20 ns					
V_{F}	0.95 V					
T _J max.	150 °C					
Package	TO-220AB, ITO-220AB, D ² PAK (TO-263AB)					
Circuit configuration	Common cathode					

FEATURES

Power pack





- · Ultrafast recovery time
- · Low switching losses, high efficiency
- Low forward voltage drop
- · High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 275 °C max., 10 s per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- AEC-Q101 qualified available
 - Automotive ordering code: base P/NHE3 (for ITO-220AB and D2PAK (TO-263AB package))
- · Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, inverters, freewheeling diodes, DC/DC converters, and other power switching application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, D2PAK (TO-263AB)

Molding compound meets UL 94V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade Base P/NHE3_X - RoHS-compliant and AEC-Q101 qualified (" X" denotes revision code e.g. A, B,....)

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	UG18ACT	UG18BCT	UG18CCT	UG18DCT	UNIT
Max. repetitive peak reverse voltage	V_{RRM}	50	100	150	200	V
Max. RMS voltage	V _{RMS}	35	70	105	140	V
Max. DC blocking voltage	V_{DC}	50	100	150	200	V
Max. average forward rectified current at $T_C = 105$ °C	I _{F(AV)}	18				А
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	175			Α	
Operating junction and storage temperature range	T _J , T _{STG}	-65 to +150			°C	
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V _{AC}	1500			V	



UG18xCT, UGF18xCT, UGB18xCT

Vishay General Semiconductor

ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	UG18ACT	UG18BCT	UG18CCT	UG18DCT	UNIT
Max. instantaneous forward voltage per diode ⁽¹⁾	9.0 A			1.1				
	20 A	T _J = 100 °C	V_{F}	1.2				
	5.0 A							
Max. DC reverse current at rated DC blocking voltage per diode		T _A = 25 °C	I _R	10				μА
		T _A = 100 °C						
Max. reverse recovery time per diode	I _F = 0.5 A, I _R = 1.0 A, I _r	_r = 0.25 A	t _{rr}	20			ns	
Max. reverse recovery time per diode	$I_F = 9.0 \text{ A}, V_R = 30 \text{ V},$	T _J = 25 °C		30				
	dI/dt = 50 A/μs, I _{rr} = 10 % I _{RM}	T _J = 100 °C	t _{rr}	50				ns
Max. stored charge per diode	$I_F = 9.0 \text{ A}, V_R = 30 \text{ V},$	T _J = 25 °C					. 0	
	dl/dt = 50 A/µs, I _{rr} = 10 % I _{RM}	T _J = 100 °C	Q _{rr}	45				nC
Typical junction capacitance per diode	at 4.0 V, 1 MHz		CJ	CJ		80		pF

Notes

 $^{^{(1)}\,}$ Pulse test: 300 μs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	UG18	UGF18	UGB18	UNIT	
Typical thermal resistance from junction to case per diode	$R_{\theta JC}$	4.0	6.0	4.0	°C/W	

ORDERING INFORMATION (EXAMPLE)								
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
TO-220AB	UG18DCT-E3/45	1.85	45	50/tube	Tube			
ITO-220AB	UGF18DCT-E3/45	2.00	45	50/tube	Tube			
TO-263AB	UGB18DCT-E3/45	1.35	45	50/tube	Tube			
TO-263AB	UGB18DCT-E3/81	1.35	81	800/reel	Tape and reel			
ITO-220AB	UGF18DCTHE3_A/P (1)	2.00	Р	50/tube	Tube			
TO-263AB	UGB18DCTHE3_A/P (1)	1.35	Р	50/tube	Tube			
TO-263AB	UGB18DCTHE3_A/I (1)	1.35	I	800/reel	Tape and reel			

Note

⁽¹⁾ AEC-Q101 qualified, available in ITO-220AB and TO-263AB package

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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

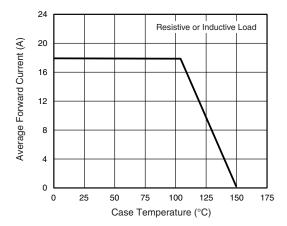


Fig. 1 - Forward Current Derating Curve

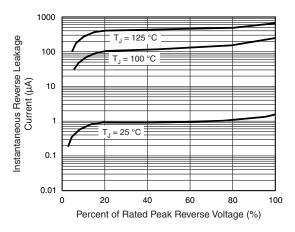


Fig. 4 - Typical Reverse Leakage Characteristics Per Diode

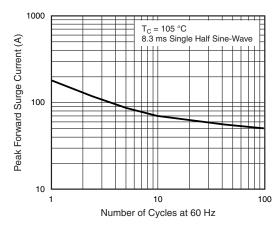


Fig. 2 - Max. Non-Repetitive Peak Forward Surge Current Per Diode

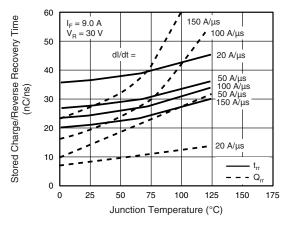


Fig. 5 - Reverse Switching Characteristics Per Diode

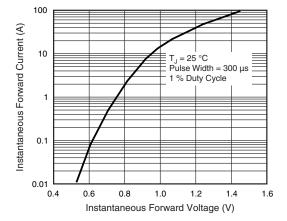


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

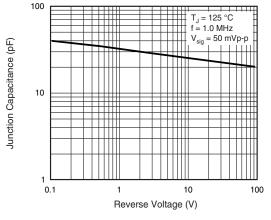
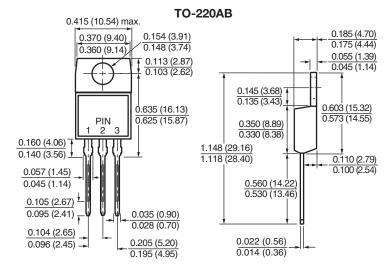


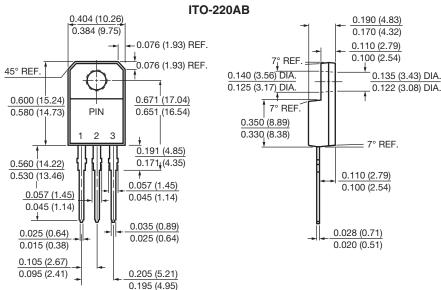
Fig. 6 - Typical Junction Capacitance Per Diode



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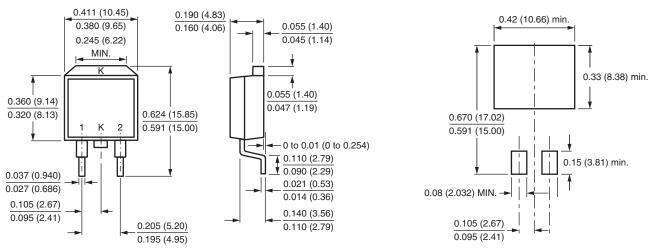
PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





D²PAK (TO-263AB)

Mounting Pad Layout





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